TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington)

2SD2584

High Power Switching Applications
Hammer Drive, Pulse Motor Drive Applications

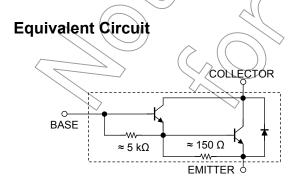
- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 3$ V, $I_{C} = 3$ A)
- Low saturation voltage: $V_{CE (sat)} = 1.5 \text{ V (max) (IC} = 3 \text{ A)}$

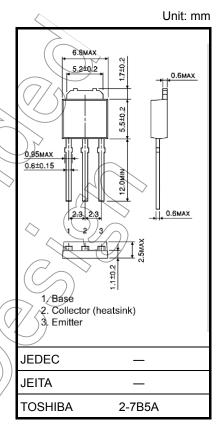
Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	120	(*)	
Collector-emitter voltage		V _{CEO}	100	(\sqrt{y})	
Emitter-base voltage		V _{EBO}	6	V	
Collector current	DC	Ic	7	A	
	Pulse	ICP	10	\supset \land	
Base current		Ι _Β	0.7	Α	
Collector power dissipation	Ta = 25°C	P _C	1.5	W	
	Tc = 25°C		20		
Junction temperature		Tj	150)sc/	
Storage temperature range		T _{stg}) -55 to 150	°C	

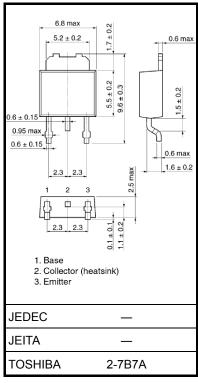
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).





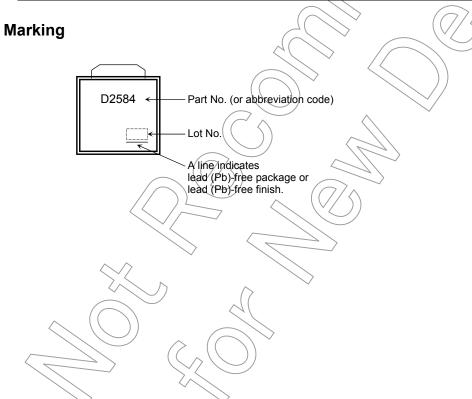
Weight: 0.36 g (typ.)



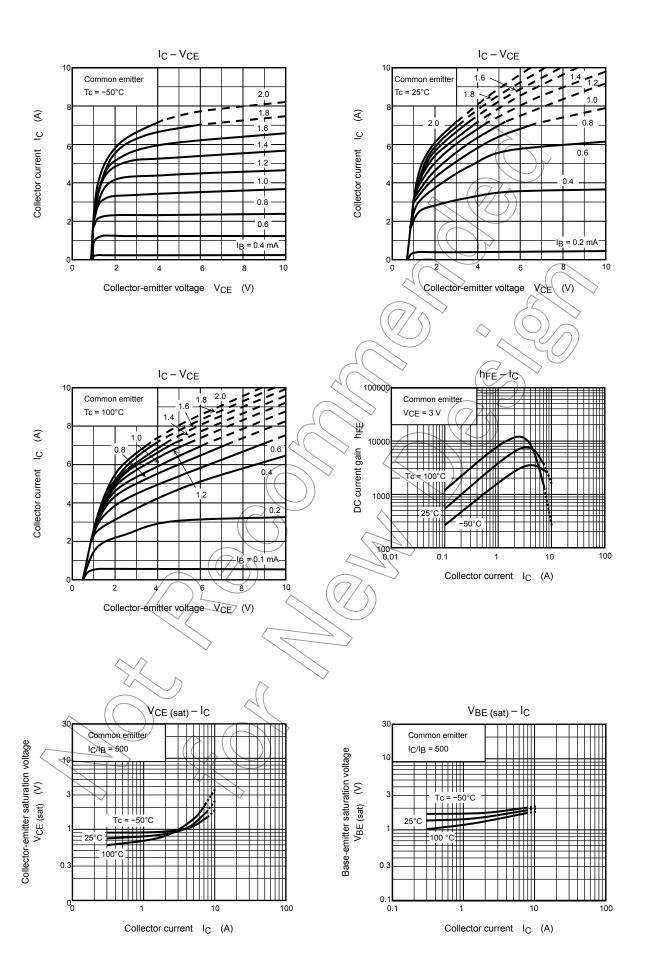
Weight: 0.36 g (typ.)

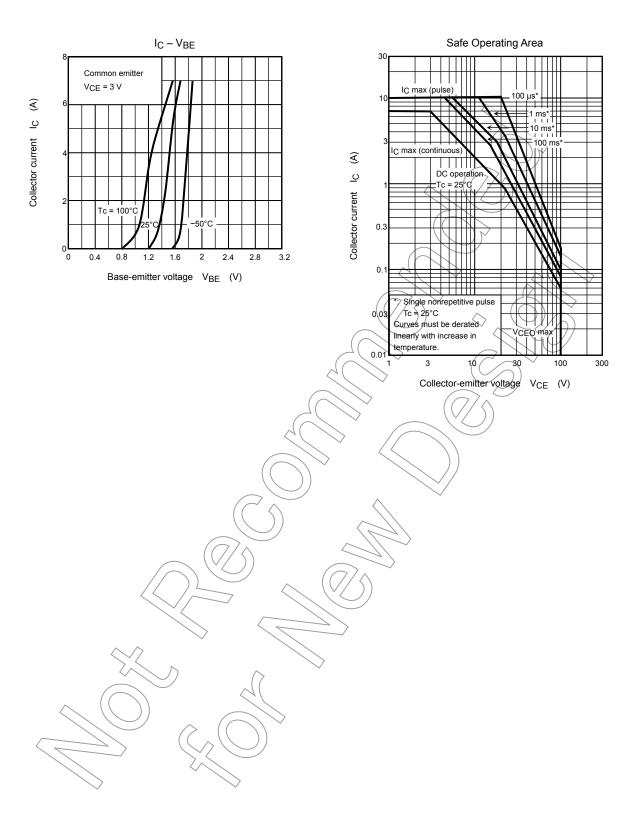
Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I _{CBO}	V _{CB} = 100 V, I _E = 0	_	_	100	μΑ
Emitter cut-off cu	rrent	I _{EBO}	V _{EB} = 6 V, I _C = 0	0.75	_	3.0	mA
Collector-emitter	breakdown voltage	V (BR) CEO	I _C = 50 mA, I _B = 0	100	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 3 V, I _C = 3 A	2000	_	15000	
		h _{FE (2)}	V _{CE} = 3 V, I _C = 6 A	1000) >-	_	
Collector-emitter	saturation voltage	V _{CE} (sat)	I _C = 3 A, I _B = 6 mA	>_	0.9	1.5	V
Base-emitter satu	ıration voltage	V _{BE (sat)}	I _C = 3 A, I _B = 6 mA	$\bigcirc)$	1.5	2.0	V
Switching time	Turn-on time	t _{on}	20 μs B1 OUTPUT	· _	0.3	-	
	Storage time	t _{stg}	PUT IB2	- (5.1	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	μs
	Fall time	t _f	$V_{CC} \approx 45 \text{ V}$ $I_{B1} = -I_{B2} = 6 \text{ mA}$ DUTY CYCLE $\leq 1\%$		0.6	_	



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